## NSN 5961-01-170-2818

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-170-2818
Inclosure Material:
Metal
Overall Length:
1.573 inches
Overall Height:
0.450 inches
Overall Width:
1.050 inches
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
T0-3
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
600.0 collector to emitter voltage, dc with specified circuit between base and emitter and 300.0 collector to emitter voltage/static/base oper
and 8.0 emitter to base voltage, static, collector open
Current Rating Per Characteristic:
Between 10.00 amperes source cutoff current and 15.00 amperes source cutoff current
Power Rating Per Characteristic:
175.0 watts small-signal input power, common-collector preset
Transfer Ratio:
60.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 pin and 1 case
Specification Data:
81349-mil-s-19500/525 government specification
Shelf Life:

N/a

**Unit Of Measure:** 

## NSN 5961-01-170-2818

Transistor - Page 2 of 2



Demilitarization:

No

Fiig:

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